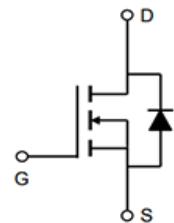


**• Product Summary**

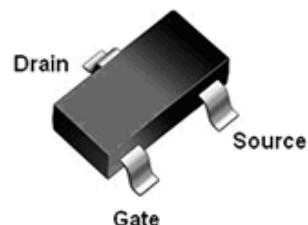
Part #	V <sub>DS</sub>	R <sub>DS(on).typ</sub> (@V <sub>GS</sub> =10V)	R <sub>DS(on).typ</sub> (@V <sub>GS</sub> =4.5V)	I <sub>D</sub>
EFM3015A	30V	15mΩ	23mΩ	6A


**• Features**

- Low R<sub>DS(on)</sub> @ V<sub>GS</sub>=10V
- 4.5V Logic Level Control
- N Channel SOT23-3L Package
- Pb-Free, RoHS Compliant

**N-Channel MOSFET**
**• Application**

- Charging switch for portable devices
- Small brushless DC motor drive
- Load Switch for PWM
- DC-to-DC converters


**• Ordering Information:**

Part NO.	EFM3015A
Marking	3015
Packing Information	REEL TAPE
Basic ordering unit (pcs)	3000

**• Absolute Maximum Ratings (T<sub>C</sub>=25°C)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Drain Current-Continuous	I <sub>D</sub>	6	A
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	23	A
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 To 150	°C

**• Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	100	°C/W
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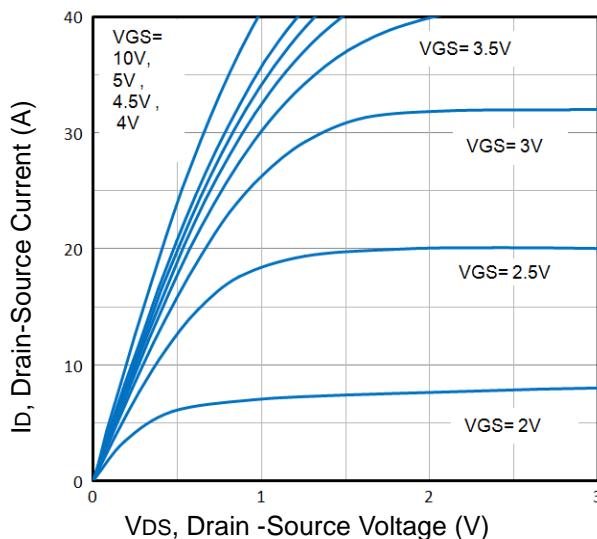
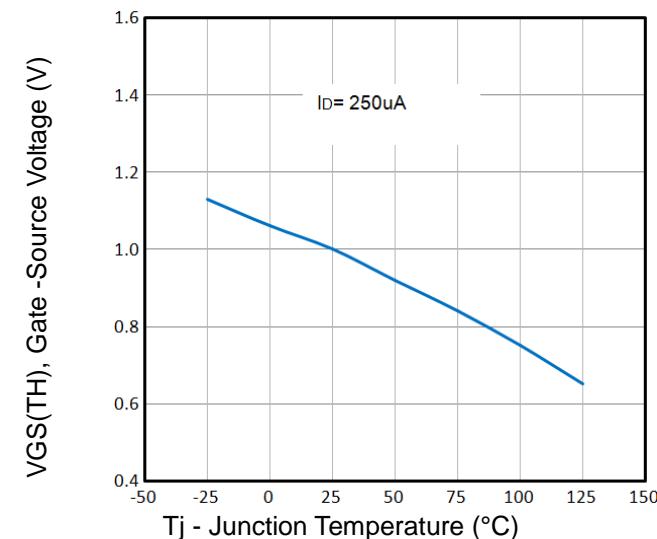
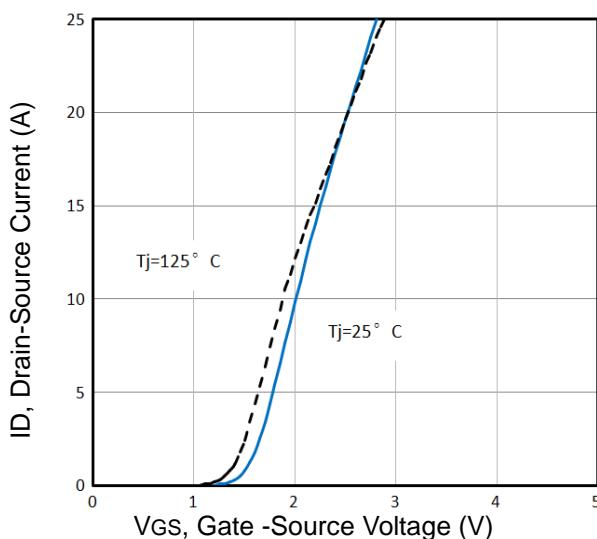
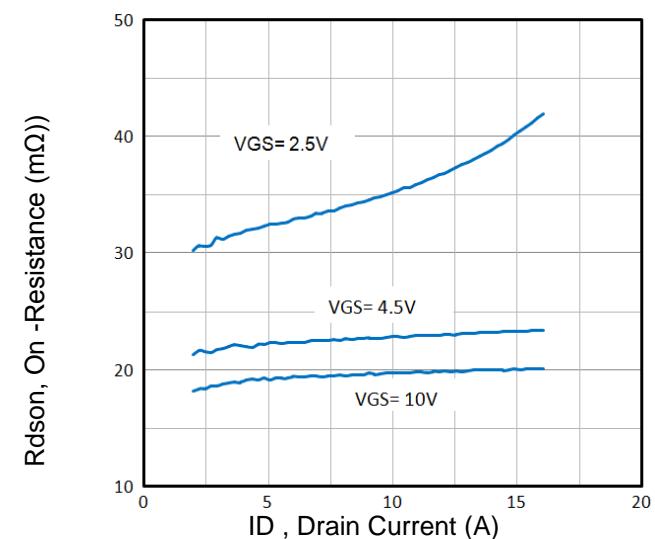
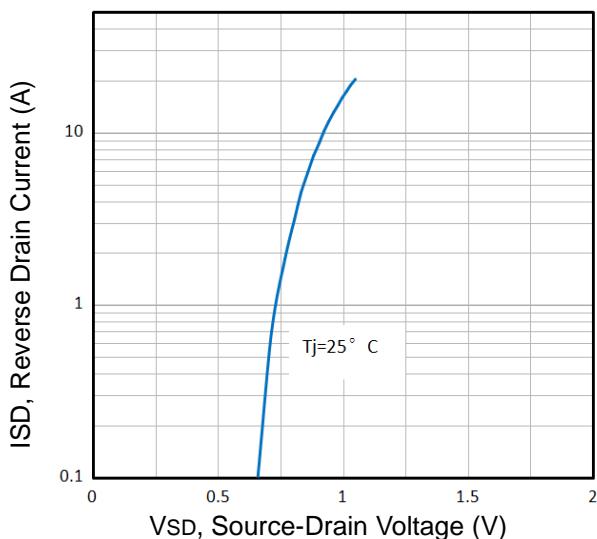
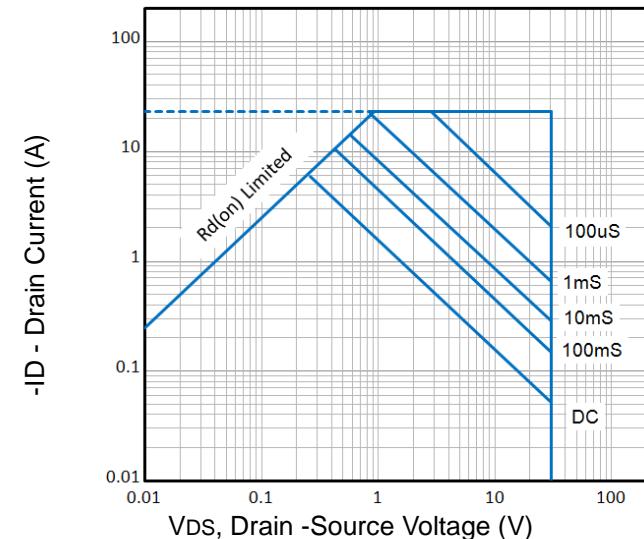
**• Static Electrical Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise stated)**

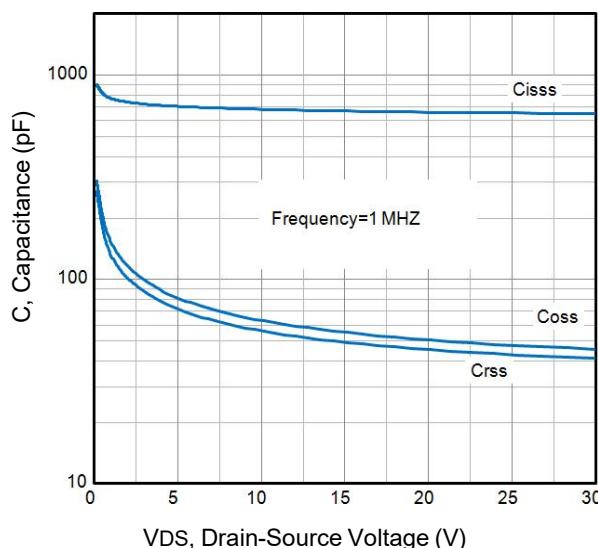
Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V} I_{\text{D}}=250\mu\text{A}$	30	--	--	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=30\text{V} V_{\text{GS}}=0\text{V}$	--	--	1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 12\text{V} V_{\text{DS}}=0\text{V}$	--	--	$\pm 100$	nA
<b>On Characteristics</b> <small>(Note 3)</small>						
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}} I_{\text{D}}=250\mu\text{A}$	0.4	0.8	1.5	V
Drain-Source On-State Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=10\text{V} I_{\text{D}}=6\text{A}$	--	15	20	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V} I_{\text{D}}=5\text{A}$	--	23	30	$\text{m}\Omega$
<b>Dynamic Characteristics</b> <small>(Note 4)</small>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=15\text{V} V_{\text{GS}}=0\text{V}$ $F=1.0\text{MHz}$	--	650	--	PF
Output Capacitance	$C_{\text{oss}}$		--	54	--	PF
Reverse Transfer Capacitance	$C_{\text{rss}}$		--	47	--	PF
<b>Switching Characteristics</b> <small>(Note 4)</small>						
Turn-on Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=15\text{V} I_{\text{D}}=5\text{A}$ $V_{\text{GS}}=4.5\text{V} R_{\text{G}}=3.3\Omega$	--	7.5	--	nS
Turn-on Rise Time	$t_r$		--	18	--	nS
Turn-Off Delay Time	$t_{\text{d(off)}}$		--	36	--	nS
Turn-Off Fall Time	$t_f$		--	5	--	nS
Total Gate Charge	$Q_g$	$V_{\text{DS}}=15\text{V} I_{\text{D}}=5\text{A}$ $V_{\text{GS}}=4.5\text{V}$	--	6.2	--	nC
Gate-Source Charge	$Q_{\text{gs}}$		--	1.2	--	nC
Gate-Drain Charge	$Q_{\text{gd}}$		--	1.9	--	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <small>(Note 3)</small>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V} I_{\text{S}}=5\text{A}$	--	0.83	1.2	V
Diode Forward Current <small>(Note 2)</small>	$I_{\text{S}}$		--	--	1.5	A

**Notes:**

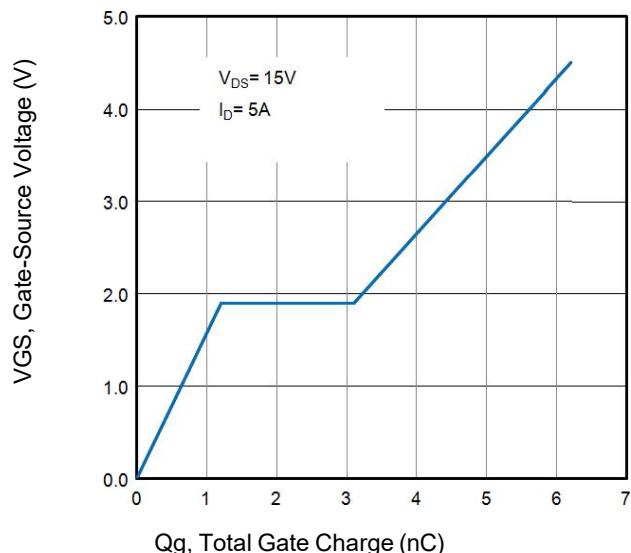
① Pulse width limited by maximum allowable junction temperature

② Pulse test ; Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

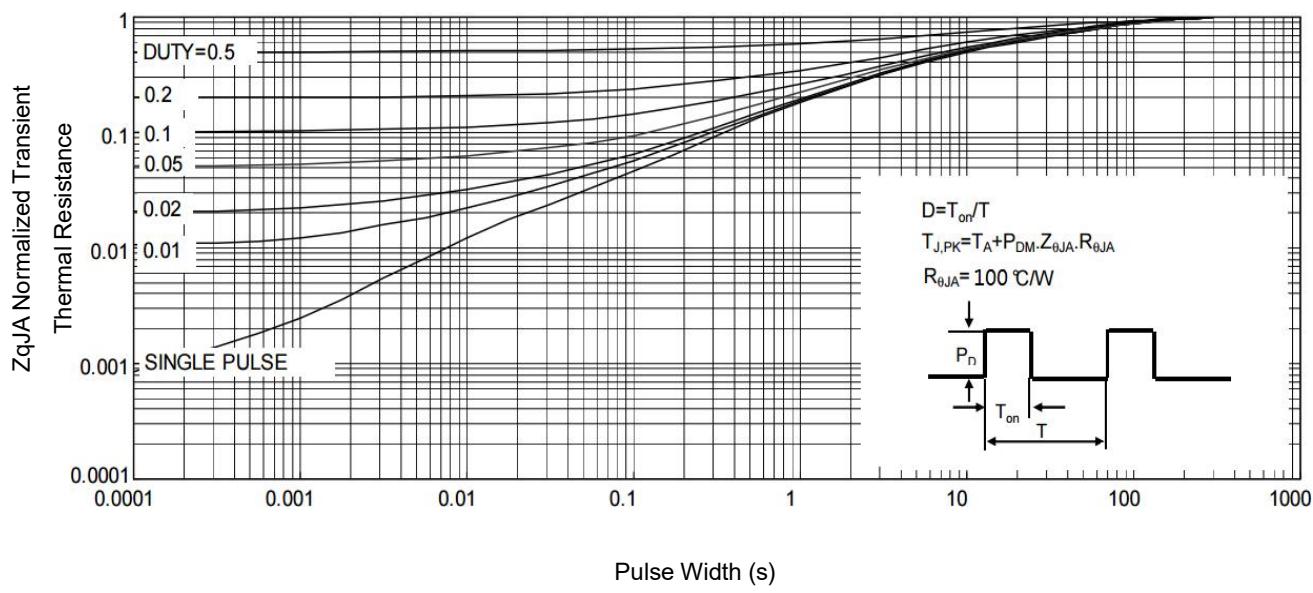
**• Typical Characteristics**

**Fig1.** Typical Output Characteristics

**Fig2.** Normalized Threshold Voltage Vs. Temperature

**Fig3.** Typical Transfer Characteristics

**Fig4.** On-Resistance vs. Drain Current and VGS

**Fig5.** Typical Source-Drain Diode Forward Voltage

**Fig6.** Maximum Safe Operating Area



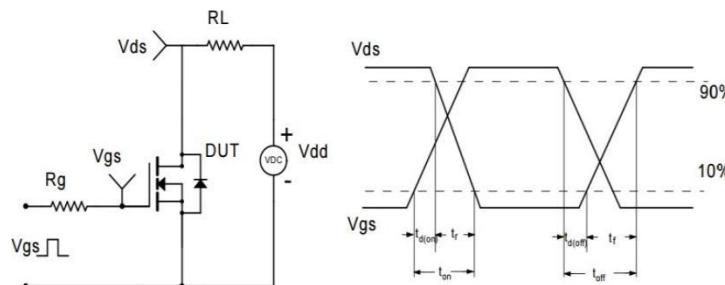
**Fig7.** Typical Capacitance Vs. Drain-Source Voltage



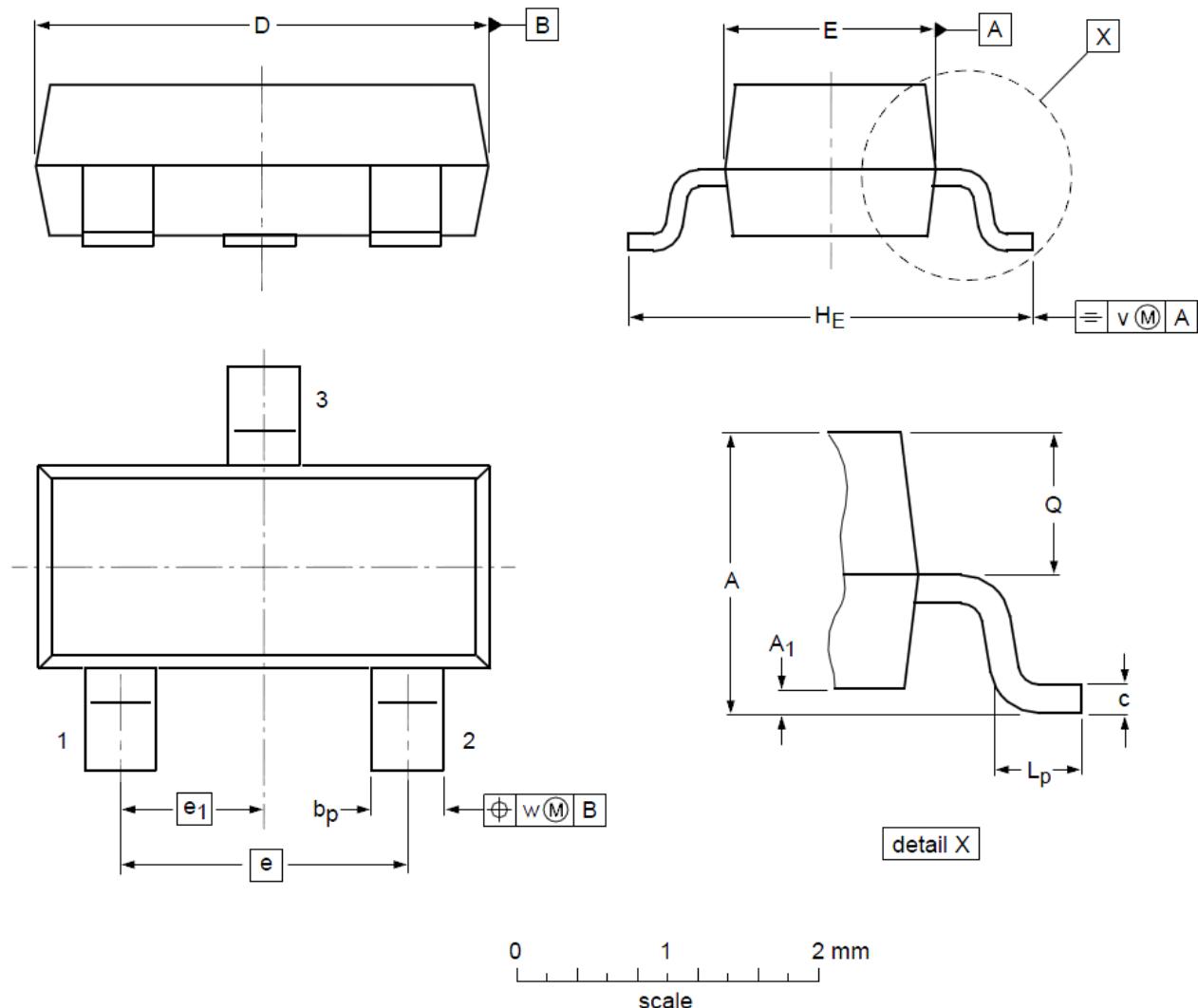
**Fig8.** Typical Gate Charge Vs. Gate-Source Voltage



**Fig9.** Normalized Maximum Transient Thermal Impedance



**Fig10.** Switching Time Test Circuit and waveforms

**SOT23-3L Package Outline Dimensions**

**DIMENSIONS (unit : mm)**

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
<b>A</b>	1.00	1.17	1.30	<b>A<sub>1</sub></b>	0.01	0.05	0.10
<b>b<sub>p</sub></b>	0.35	0.39	0.50	<b>c</b>	0.10	0.20	0.26
<b>D</b>	2.70	2.90	3.10	<b>E</b>	1.30	1.58	1.70
<b>e</b>	--	1.90	--	<b>e<sub>1</sub></b>	--	0.95	--
<b>H<sub>E</sub></b>	2.50	2.78	3.00	<b>L<sub>p</sub></b>	0.20	0.32	0.60
<b>Q</b>	0.23	0.27	0.33	<b>v</b>	--	0.20	--
<b>w</b>	--	0.20	--				